

SIDE LOOK PACKAGE

NPN PHOTOTRANSISTOR

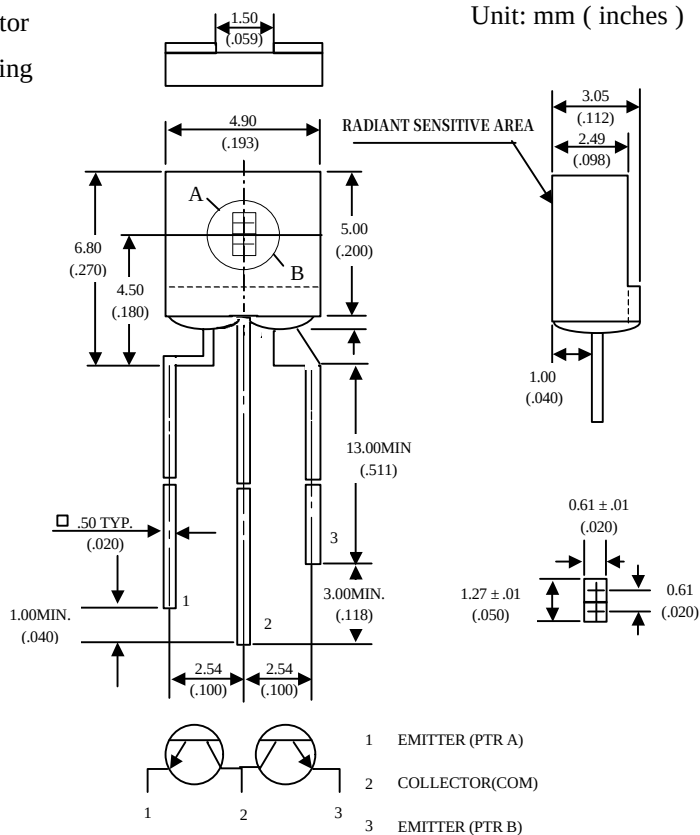
MID-95R3L

Description

The MID-95R3L is a TWIN NPN silicon phototransistor mounted in a special red transparent plastic side looking package.

Package Dimensions

Unit: mm (inches)



Features

- Wide range of collector current

NOTES :

1. All dimensions are in millimeters.(inches).
2. Tolerance is $\pm 0.25\text{mm}$ (.010") unless otherwise noted .
3. Protruded resin under flange is 1.5mm (.059") max.
4. Lead spacing is measured where the leads emerge from the package.

Absolute Maximum Ratings

@ $T_A = 25^\circ\text{C}$

Parameter	Maximum Rating	Unit
Power Dissipation	100	mW
Collector-Emitter Voltage	30	V
Emitter-Collector Voltage	5	V
Operating Temperature Range	-55°C to $+100^\circ\text{C}$	
Storage Temperature Range	-55°C to $+100^\circ\text{C}$	
Lead Soldering Temperature	260°C for 5 seconds	

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Optical-Electrical Characteristics

@ $T_A=25^{\circ}\text{C}$

Parameter	Test Conditions	Symbol	Min.	Typ .	Max.	Unit
Collector-Emitter Breakdown Voltage	$I_c=0.1\text{mA}$ $E_e=0$	$V_{(BR)CEO}$	30			V
Emitter-Collector Breakdown Voltage	$I_e=0.1\text{mA}$ $E_e=0$	$V_{(BR)ECO}$	5			V
Collector-Emitter Saturation Voltage	$I_c=0.5\text{mA}$ $E_e=0.1\text{mW/cm}^2$	$V_{CE(SAT)}$		0.1	0.4	V
Rise Time	$V_R=5\text{V}$, $R_L=1\text{K}\Omega$	T_r		10		μS
Fall Time	$I_c=1\text{mA}$	T_f		10		
Collector Dark Current	$V_{CE}=10\text{V}$ $E_e=0$	I_{CEO}			100	nA
On State Collector Current	$V_{CE}=5\text{V}$ $E_e=0.1\text{mW/cm}^2$	$I_{C(ON)}$		0.4		mA

Typical Optical-Electrical Characteristic Curves

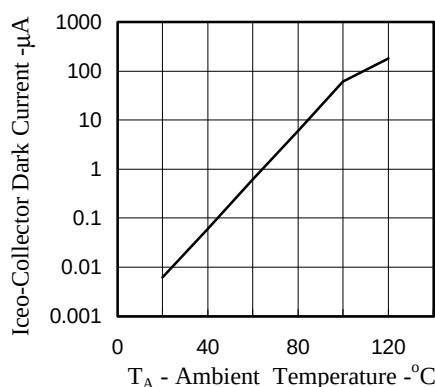


FIG.1 COLLECTOR DARK CURRENT VS AMBIENT TEMPERATURE

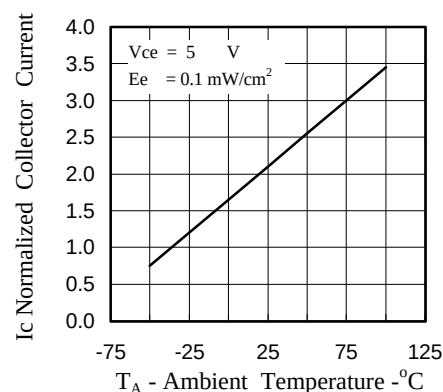


FIG.2 NORMALIZED COLLECTOR CURRENT VS AMBIENT TEMPERATURE

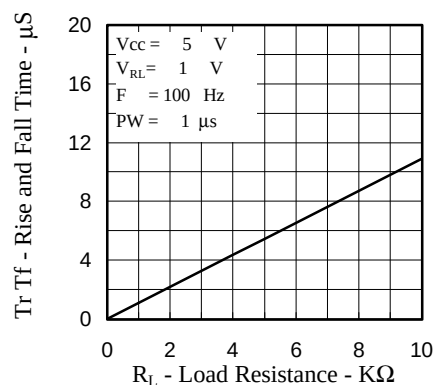


FIG.3 RISE AND FALL TIME VS LOAD RESISTANCE

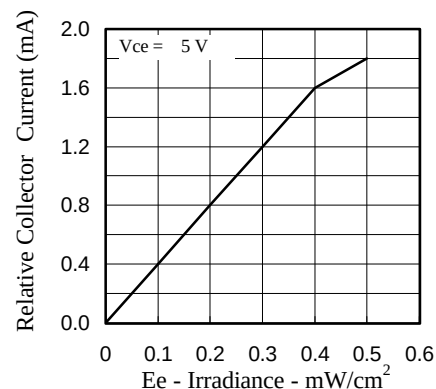


FIG.4 RELATIVE COLLECTOR CURRENT VS IRRADIANCE